

In-situ analysis of conductive films formation by adaptable Cu nanocrystals

Arnau Oliva Puigdomènech¹ | Jonathan De Roo^{1,2} | Filip Geenen³ Christophe Detavernier^{1,3} | José Martins^{1,4} | Zeger Hens^{1,5}

Copper nanocrystals (Cu NCs) are extensively studied for its applications in printed electronics due to their excellent conductive properties. However, its sensibility to oxidation restrains its introduction to the market. An approach to reverse the oxidation and form a compact and conductive film is thermal sintering.

We investigated the effect of:

Surface chemistry and particle size on the sintering of Cu NCs films



SIZE TUNING



Surface composition



Temperature (°C)

Size (nm)

Resistivity could be reduced down to $20\mu\Omega$ ·cm after sintering

- A versatile synthesis protocol and a modifiable surface enabled the study of the role of the particle size and surface chemistry during the sintering of Cu NCs.
- Short and volatile ligands are released easily during sintering, facilitating the reduction process and providing larger grain size to the films.
- Large particles present a better inherent conductivity yet they require heavier conditions to fully reduce and sinter.

AFFILIATIONS

1. Physics and Chemistry of Nanostructures, Department of Chemistry, Ghent University, Krijgslaan 281 (S3), 9000 Gent, Belgium.

Sol-gel Centre for Research on Inorganic Powders and Thin films Synthesis, Ghent University, Ghent, Belgium
Conformal Coating of Nanomaterials, Department of Physics, Ghent University, Krijgslaan 281 (S1), 9000 Gent, Belgium.

4. NMR and Structural Analysis Unit, Department of Organic Chemistry, Ghent University, Krijgslaan 281 (S4), 9000 Gent, Belgium.

5. Belgium Center for Nano and Biophotonics, Ghent University, 9000 Gent, Belgium

Clusters for Growth